

isc N-Channel MOSFET Transistor

IXTA2R4N50P

• FEATURES

- Static drain-source on-resistance:
 R_{DS}(on) ≤ 3.75Ω@V_{GS}=10V
- Fully characterized avalanche voltage and current
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATION

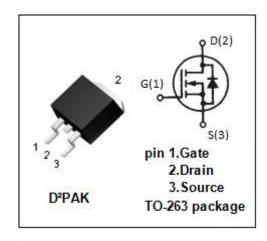
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

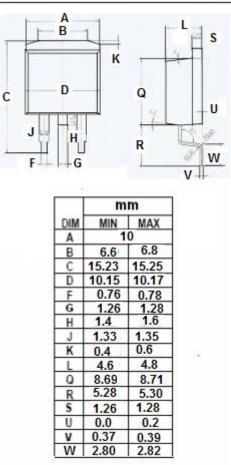
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
$V_{ extsf{DSS}}$	Drain-Source Voltage	500	V	
V _{GS}	Gate-Source Voltage	±30	V	
Ι _D	Drain Current-Continuous	2.4	А	
I _{DM}	Drain Current-Single Pulsed	4.5	А	
P _D	Total Dissipation @Tc=25°C	55	W	
Tj	Operating Junction Temperature	-55~150	$^{\circ}$ C	
T _{stg}	Storage Temperature	-55~150	$^{\circ}$ C	

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{\text{th(j-c)}}$	Junction-to-case thermal resistance	2.27	°C/W







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; ID =250 μ A	500		V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} ; ID =250 μ A	3.0	5.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D = 1.2A		3.75	Ω
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±30V;V _{DS} =0V		±50	nA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = V _{DSS} ; V _{GS} = 0V		1	- μΑ
		V _{DS} = V _{DSS} ; V _{GS} = 0V;T _J = 125°C		50	
V _{SD}	Diode forward voltage	I _F = 2.4A; V _{GS} = 0V		1.5	V



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